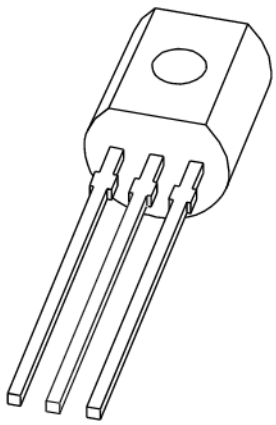
DATA SHEET



BC337
NPN general purpose transistor

Product specification
Supersedes data of 1997 Mar 10

1999 Apr 15

Philips
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NPN general purpose transistor BC337

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 45 V).

APPLICATIONS

- General purpose switching and amplification, e.g. driver and output stages of audio amplifiers.

DESCRIPTION

NPN transistor in a TO-92; SOT54 plastic package.
PNP complement: BC327.

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	collector

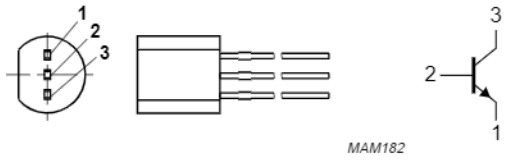


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	−	50	V
V_{CEO}	collector-emitter voltage	open base	−	45	V
V_{EBO}	emitter-base voltage	open collector	−	5	V
I_C	collector current (DC)		−	500	mA
I_{CM}	peak collector current		−	1	A
I_{BM}	peak base current		−	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	−	625	mW
T_{stg}	storage temperature		−65	+150	°C
T_j	junction temperature		−	150	°C
T_{amb}	operating ambient temperature		−65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	0.2	K/mW

Note

1. Transistor mounted on an FR4 printed-circuit board.

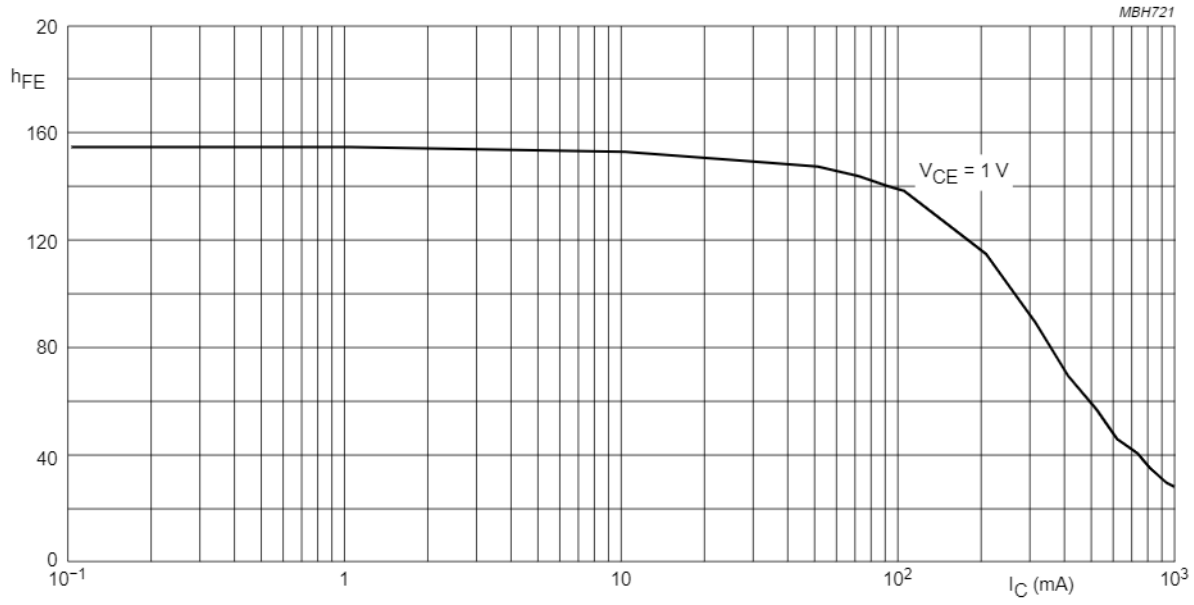
CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current	I_E = 0; V_{CB} = 20 V	–	–	100	nA
		I_E = 0; V_{CB} = 20 V; T_j = 150 °C	–	–	5	∝A
I_{EBO}	emitter cut-off current	I_C = 0; V_{EB} = 5 V	–	–	100	nA
h_{FE}	DC current gain	I_C = 100 mA; V_{CE} = 1 V; see Figs 2, 3 and 4				
	BC337		100	–	600	
	BC337-16		100	–	250	
	BC337-25		160	–	400	
	BC337-40		250	–	600	
	DC current gain	I_C = 500 mA; V_{CE} = 1 V; see Figs 2, 3 and 4	40	–	–	
V_{CEsat}	collector-emitter saturation voltage	I_C = 500 mA; I_B = 50 mA	–	–	700	mV
V_{BE}	base-emitter voltage	I_C = 500 mA; V_{CE} = 1 V; note 1	–	–	1.2	V
C_c	collector capacitance	I_E = i_e = 0; V_{CB} = 10 V; f = 1 MHz	–	5	–	pF
f_T	transition frequency	I_C = 10 mA; V_{CE} = 5 V; f = 100 MHz	100	–	–	MHz

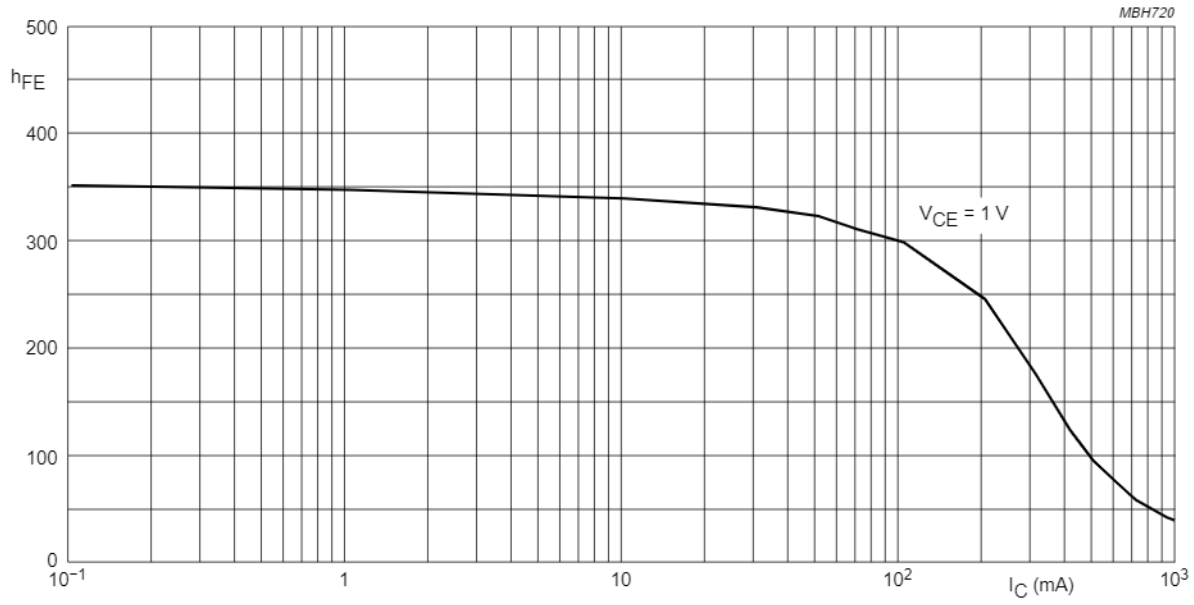
Note

1. V_{BE} decreases by about 2 mV/K with increasing temperature.



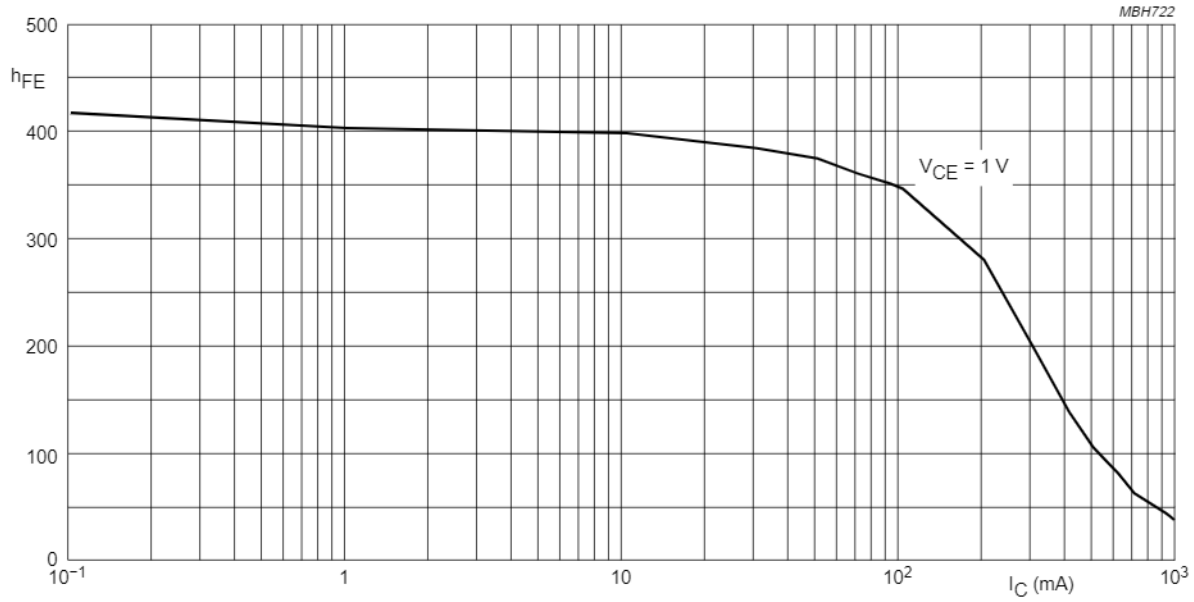
BC337-16.

Fig.2 DC current gain; typical values.



BC337-25.

Fig.3 DC current gain; typical values.

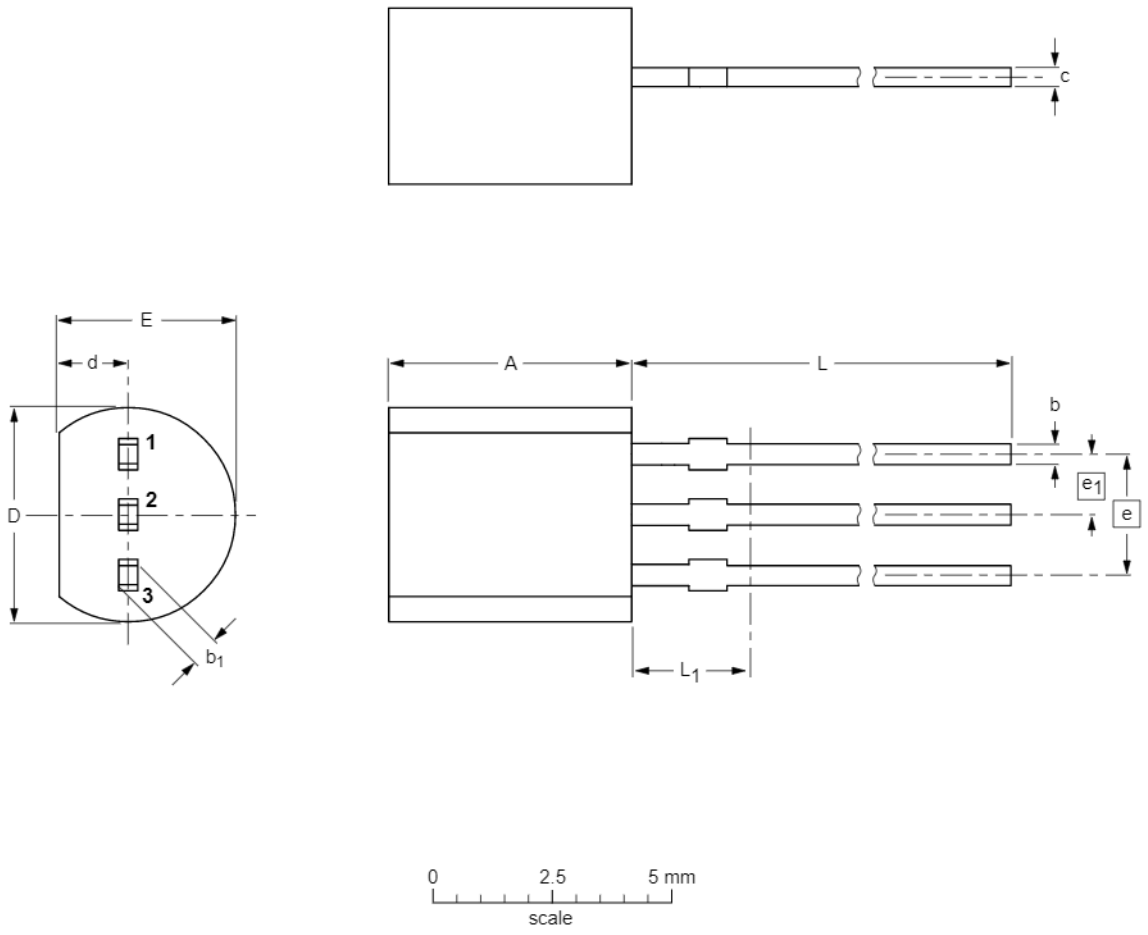


BC337-40.

Fig.4 DC current gain; typical values.

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads **SOT54**



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b_1	c	D	d	E	e	e_1	L	L_1(1)
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT54		TO-92	SC-43			97-02-28

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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